



# INTERNATIONAL SEMICONDUCTOR, Inc.

**SUPER FAST RECOVERY, GLASS PASSIVATED, PLASTIC RECTIFIERS**  
**VOLTAGE - 50 TO 400 Volts      CURRENT - 30.0 Ampere**

## SF301 thru SF306

### FEATURES:

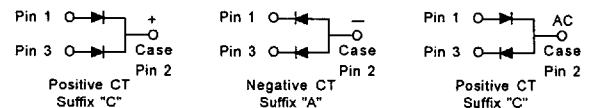
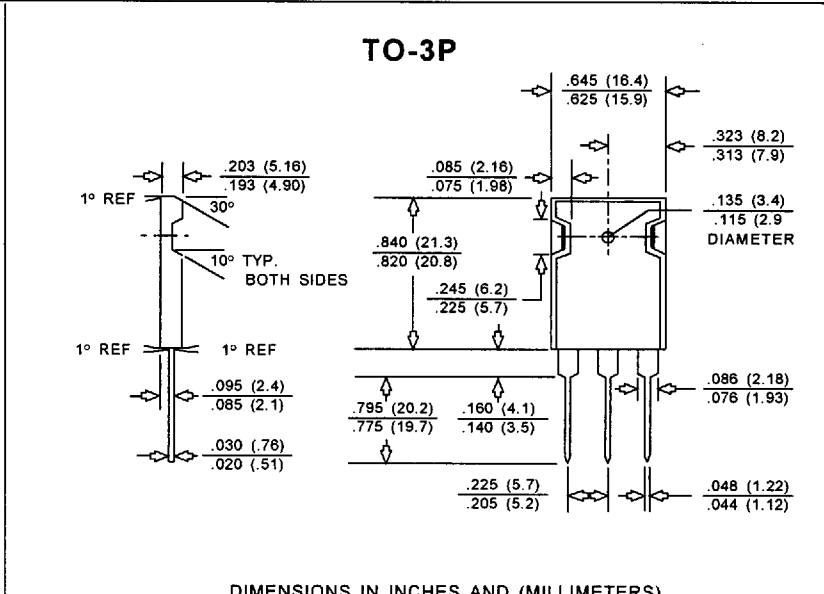
Dual rectifier construction, positive centertap  
 Plastic material used carries Underwriters  
 Laboratory recognition 94 V-O  
 High Surge Capability  
 Superfast recovery times, high voltage  
 Low forward voltage, high current capability  
 Low thermal resistance  
 Low Power Loss, high efficiency  
 High temperature soldering guaranteed -  
 250 °C for 10 seconds

### MECHANICAL DATA:

CASE: Transfer molded plastic case  
 TERMINALS: Plated terminals, solderable per  
 MIL-STD-202, Method 208  
 POLARITY: As marked  
 MOUNTING POSITION: Any  
 WEIGHT: 0.198 Ounce (5.60 Gram)

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified  
 Single phase, half wave, 60 Hz, resistive or inductive load  
 For capacitive load, derate current by 20%



	SYMBOL	SF301	SF302	SF303	SF304	SF305	SF306	UNIT
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	150	200	300	400	V
Maximum RMS Input Voltage	$V_{RMS}$	35	70	105	140	210	280	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	150	200	300	400	V
Maximum Average Forward Current .375"(9.5mm) Lead Length, $T_L = 90^\circ\text{C}$	$I_{(AV)}$	30						A
Peak Forward Surge Current - 8.3 ms single half sine wave superimposed on rated load	$I_{FSM}$	300						A
Maximum Instantaneous Forward Voltage at 15A	$V_F$	0.975				1.3		V
Maximum DC Reverse Current at Rated DC Blocking Voltage	$I_R$	10						uA
	$I_R$	200						uA
Maximum Recovery Time (Note 1)	$T_{RR}$	35						ns
Typ Junction Capacitance $T_J=25^\circ\text{C}$ (Note 2)	$C_J$	170				130		pf
Typical Thermal Resistance (Note 3)	$R_{\theta JC}$	1.00						°C/W
Operating Temperature Range	$T_J$	-65 to +150						°C
Storage Temperature Range	$T_{STG}$	-65 to +150						°C

Note 1: Reverse Recovery Conditions:  $I_F=0.5A$ ,  $I_R=1.0A$ ,  $I_{RR}=0.25A$   
 Note 2: Measured at 1.0 MHz and 4.0 Volt Bias Voltage  
 Note 3: Thermal Resistance from Junction to case per element

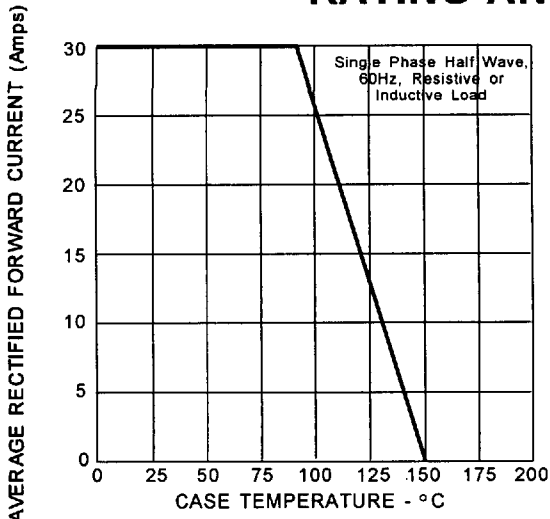
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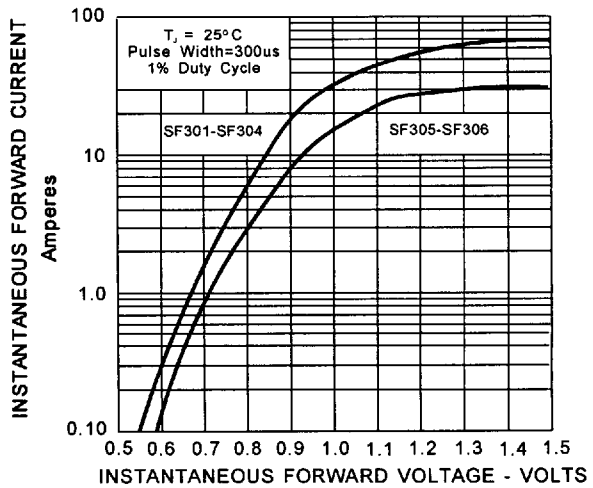
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# SF301 thru SF306

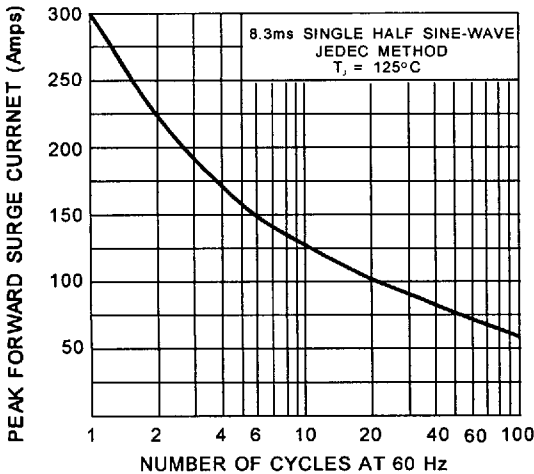
## RATING AND CHARACTERISTIC CURVES



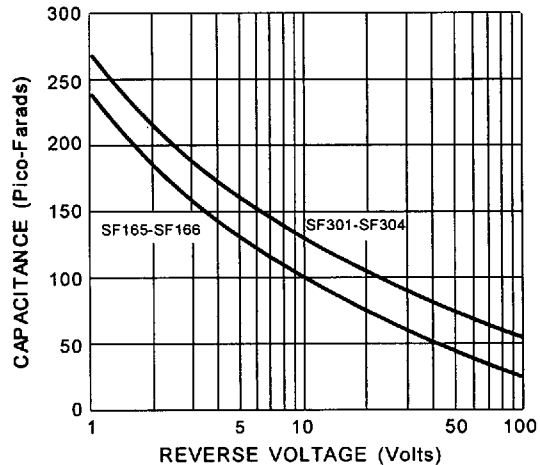
**FIG. 2 - FORWARD CURRENT DERATING CURVE**



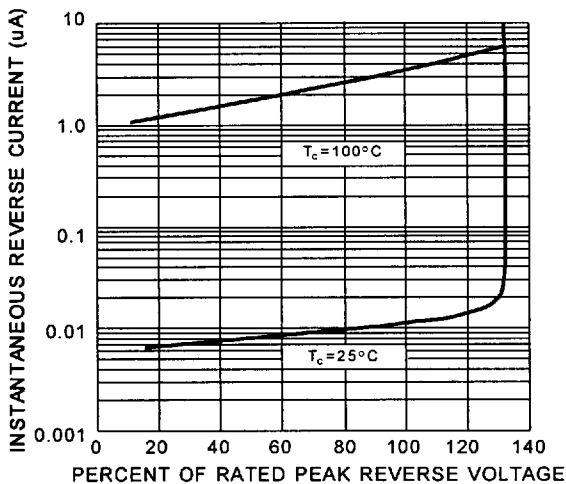
**FIG. 3 - TYPICAL FORWARD CHARACTERISTICS**



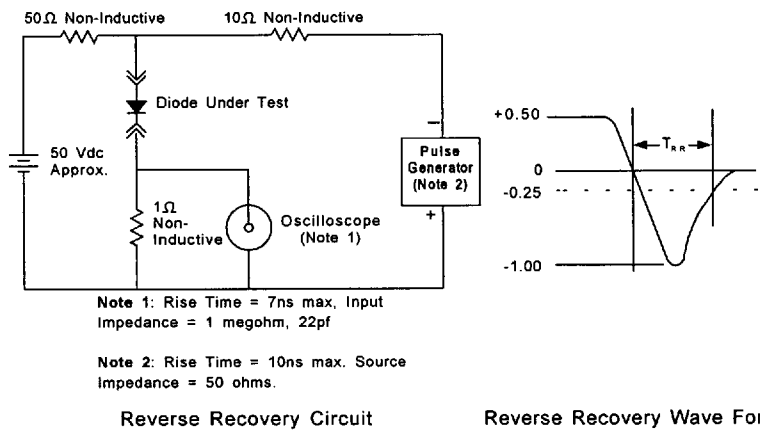
**FIG. 4 - MAXIMUM NON-REPETITIVE PEAK SURGE CURRENT**



**FIG. 5 - TYPICAL JUNCTION CAPACITANCE**



**FIG. 5 TYPICAL REVERSE CHARACTERISTICS**



**Fig. 7 - REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM**

**INTERNATIONAL SEMICONDUCTOR, INC.**

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